# **CATV** Amplifier Module

# Features

Technical Data

- · Specified for 77-, 110- and 128-Channel Loading
- Excellent Distortion Performance

**Freescale Semiconductor** 

- Superior Gain, Return Loss and DC Current Stability over Temperature
- Silicon Bipolar Transistor Technology
- Unconditionally Stable Under All Load Conditions

# Applications

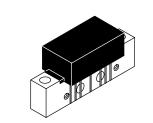
- CATV Systems Operating in the 40 to 860 MHz Frequency Range
- Input Stage Amplifier in Optical Nodes, Line Extenders and Trunk Distribution Amplifiers for CATV Systems
- Driver Amplifier in Linear General Purpose Applications
- Output Stage Amplifier on Applications Requiring Low Power Dissipation **Description**
- Description
- 24 Vdc Supply, 40 to 860 MHz, CATV Forward Amplifier Module
- Replaced MHW8182C. There are no form, fit or function changes with this part replacement.
- RoHS Compliant

INFORMA

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**MHW8182CN** 

860 MHz 19.1 dB GAIN 128-CHANNEL CATV AMPLIFIER MODULE



CASE 1302-01, STYLE 1

# Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
RF Voltage Input (Single Tone)	V <sub>in</sub>	+70	dBmV
DC Supply Voltage	V <sub>CC</sub>	+28	Vdc
Operating Case Temperature Range	T <sub>C</sub>	-20 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +100	°C

Table 2. Electrical Characteristics (V<sub>CC</sub> = 24 Vdc, T<sub>C</sub> = +30°C, 75  $\Omega$  system unless otherwise noted)

Characteristic Frequency Range		Symbol	Min	Тур	Max	Unit
		BW	40	<u> </u>	860	MHz
Power Gain	50 MHz 860 MHz	G <sub>p</sub>	18 18.2	18.5 19.1	19 20.5	dB
Slope 40 - 860 MHz		S	0	0.7	2.5	dB
Gain Flatness (40 - 860 MHz, Peak to Valley)		G <sub>F</sub>	—	0.3	0.6	dB
Return Loss — Input/Output (Z <sub>o</sub> = 75 Ohms) @ 40 MHz @ f > 40 MHz (Derate)		IRL/ORL	20		0.005	dB dB/MHz
Composite Second Order (V <sub>out</sub> = +38 dBmV/ch., Worst Case) (V <sub>out</sub> = +40 dBmV/ch., Worst Case) (V <sub>out</sub> = +44 dBmV/ch., Worst Case)	128-Channel FLAT 110-Channel FLAT 77-Channel FLAT	CSO <sub>128</sub> CSO <sub>110</sub> CSO <sub>77</sub>		- 71 - 70 - 70	- 64 - 63 - 64	dBc



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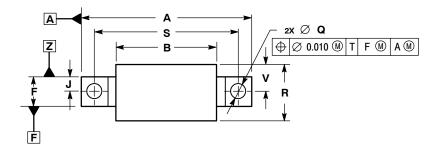
**VRoHS** 

Characteristic		Symbol	Min	Тур	Max	Unit dBc
Cross Modulation Distortion @ Ch 2						
(V <sub>out</sub> = +38 dBmV/ch., FM = 55 MHz)	128-Channel FLAT	XMD <sub>128</sub>	_	-68	-65	
$(V_{out} = +40 \text{ dBmV/ch.}, \text{FM} = 55 \text{ MHz})$	110-Channel FLAT	XMD <sub>110</sub>	_	-66	-64	
$(V_{out} = +44 \text{ dBmV/ch.}, \text{FM} = 55 \text{ MHz})$	77-Channel FLAT	XMD <sub>77</sub>	_	-61	-59	
Composite Triple Beat						dBc
(V <sub>out</sub> = +38 dBmV/ch., Worst Case)	128-Channel FLAT	CTB <sub>128</sub>	_	-69	-66	
(V <sub>out</sub> = +40 dBmV/ch., Worst Case)	110-Channel FLAT	CTB <sub>110</sub>	_	-68	-66	
(V <sub>out</sub> = +44 dBmV/ch., Worst Case)	77-Channel FLAT	CTB <sub>77</sub>	-	-66	-64	
Noise Figure	50 MHz	NF	_	4.0	5.0	dB
	550 MHz		_	4.5	—	
	750 MHz		_	5.0	6.5	
	860 MHz		-	5.5	7.5	
DC Current ( $V_{DC}$ = 24 V, $T_{C}$ = 30°C)		I <sub>DC</sub>	180	220	240	mA

# **ARCHIVE INFORMATION**

# MHW8182CN

# PACKAGE DIMENSIONS

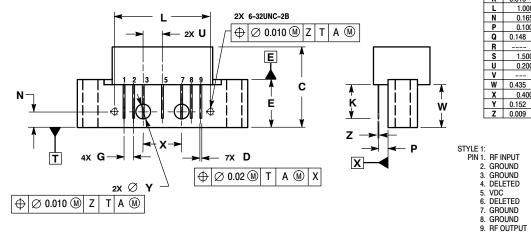


NOTES:

CONTROLLING DIMENSION: INCH.
INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α		1.775		45.085	
В		1.085		27.559	
C		0.840		21.336	
D	0.015	0.021	0.381	0.533	
Ε	0.465	0.510	11.811	12.954	
F	0.300	0.325	7.620	8.255	
G	0.100	BSC	2.540 BSC		
J	0.156	0.156 BSC		2 BSC	
K	0.315	0.355	8.001	9.017	
L	1.000 BSC		25.400 BSC		
N	0.165 BSC		4.191 BSC		
Ρ	0.100 BSC		2.540 BSC		
Q	0.148	0.168	3.759	4.267	
R		0.600		15.240	
S	1.500 BSC		38.100 BSC		
U	0.200	0.200 BSC		BSC	
۷		0.250		6.350	
W	0.435		11.049		
X	0.400 BSC 10.160 BSC		0 BSC		
Y	0.152	0.163	3.861	4.140	
Z	0.009	0.011	0.229	0.279	





CASE 1302-01 **ISSUE E** 

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